## Mascon <br> <br> GaAs SP2T 2.7V High Power Switch <br> <br> GaAs SP2T 2.7V High Power Switch <br> <br> DC - 3 GHz <br> <br> DC - 3 GHz <br> 

## Features

■ Low Voltage Operation: 2.7 V

- High IP3: +56 dBm

■ Low Insertion Loss: 0.30 dB at 1 GHz

- High Isolation: 25 dB at 1 GHz
- Miniature Package: SC70 (6L)
- 0.5 micron GaAs PHEMT Process


## Description

M/A-COM's MASWSSO117 is a GaAs PHEMT MMIC single pole two throw (SP2T) high power switch in a low cost SC70 six lead package. The MASWSS0117 is ideally suited for applications where high power, low control voltage, low insertion loss, high isolation, small size and low cost are required.

Typical applications are for CDMA handset systems that connect separate transceiver and/or GPS functions to a common antenna, as well as other related handset and general purpose applications. The MASWSS0117 can be used in all systems operating up to 3 GHz requiring high power at low control voltage.

The MASWSS0117 is fabricated using a 0.5 micron gate length GaAs PHEMT process. The process features full passivation for performance and reliability.

## Ordering Information

| Part Number | Package |
| :---: | :---: |
| MASWSS0117 | Bulk Packaging |
| MASWSS0117TR | 1000 piece reel |
| MASWSS0117TR-3000 | 3000 piece reel |
| MASWSS0117SMB | Sample Test Board |

Note: Reference Application Note M513 for reel size information.

## Functional Block Diagram



Pin Configuration

| PIN No. | PIN Name | Description |
| :---: | :---: | :---: |
| 1 | V2 | Vcontrol 2 |
| 2 | RFC | RF Common |
| 3 | V1 | Vcontrol 1 |
| 4 | RF1 | RF Port 1 |
| 5 | GND | RF Ground |
| 6 | RF2 | RF Port 2 |

MASWSS0117 orientation in tape


MASWSS0117 Device Marking


■ North America: Tel. (800) 366-2266
■ Asia/Pacific: Tel.+81-44-844-8296, Fax +81-44-844-8298
■ Europe: Tel. +44 (1908) 574200, Fax+44 (1908) 574300

Electrical Specifications: $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{Vc}=0 \mathrm{~V} / 2.7 \mathrm{~V}, \mathrm{Z}_{0}=50 \mathrm{Ohms}{ }^{1}$

| Parameter | Test Conditions | Units | Min. | Typ. | Max. |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Insertion Loss ${ }^{2}$ | $\begin{gathered} \mathrm{DC}-1 \mathrm{GHz} \\ 1-2 \mathrm{GHz} \\ 2-3 \mathrm{GHz} \end{gathered}$ | $\begin{aligned} & \mathrm{dB} \\ & \mathrm{~dB} \\ & \mathrm{~dB} \end{aligned}$ | 二 | $\begin{aligned} & 0.30 \\ & 0.35 \\ & 0.35 \end{aligned}$ | $\begin{gathered} 0.65 \\ - \end{gathered}$ |
| Isolation | $\begin{gathered} \mathrm{DC}-1 \mathrm{GHz} \\ 1-2 \mathrm{GHz} \\ 2-3 \mathrm{GHz} \end{gathered}$ | $\begin{aligned} & \mathrm{dB} \\ & \mathrm{~dB} \\ & \mathrm{~dB} \end{aligned}$ | $\begin{aligned} & 23 \\ & - \end{aligned}$ | $\begin{aligned} & 25 \\ & 19 \\ & 15 \end{aligned}$ | - |
| Return Loss | DC-3 GHz | dB | - | 20 | - |
| IP3 | $825 \text { MHz }$ <br> Two Tone, +24 dBm Total Pin, 5 MHz Spacing | dBm | - | 56 | - |
| Cross Modulation | For Cell Band: Two-tone signal input: Tx1 = +22 dBm @ 820 MHz , Tx2 = +22 dBm @ 821 MHz , RX interfere $=-23 \mathrm{dBm} @ 869 \mathrm{MHz}$. | dBm | - | -99 | - |
|  | For PCS Band: Two-tone signal input: Tx1 = +18 dBm @ 1880 MHz , Tx2 = +18 dBm @ 1881 MHz , $R X$ interfere $=-23 \mathrm{dBm} @ 1960 \mathrm{MHz}$. | dBm | - | -94 | - |
| P0.1dB | 1 GHz | dBm | - | 38 | - |
| Trise, Tfall | 10\% to 90\% RF, $90 \%$ to $10 \%$ RF | nS | - | 70 | - |
| Ton, Toff | $50 \%$ control to $90 \%$ RF, $50 \%$ control to $10 \%$ RF | nS | - | 100 | - |
| Transients | In Band | mV | - | 25 | - |
| Control Current | $\mathrm{Vc}=2.7 \mathrm{~V}$ | $\mu \mathrm{A}$ | - | 5 | 20 |

1. For positive voltage control, external DC blocking capacitors are required on all RF ports.
2. Insertion loss can be optimized by varying the DC blocking capacitor value, e.g. 1000 pF for $100 \mathrm{MHz}-1 \mathrm{GHz}, 39 \mathrm{pF}$ for $0.5 \mathrm{GHz}-3 \mathrm{GHz}$.

## Absolute Maximum Ratings ${ }^{3}$

| Parameter | Absolute Maximum |
| :---: | :---: |
| Max Input Power | +38 dBm |
| $(0.5-3 \mathrm{GHz}, 3 \mathrm{~V}$ Control $)$ | +8.5 volts |
| Operating Voltage | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ |
| Operating Temperature | $-65^{\circ} \mathrm{C}$ to $+150^{\circ} \mathrm{C}$ |
| Storage Temperature |  |

3. Exceeding any one or combination of these limits may cause permanent damage to this device.

## Truth Table ${ }^{4,5,6}$

| V1 | V2 | ANT- RF1 | ANT - RF2 |
| :---: | :---: | :---: | :---: |
| 1 | 0 | On | Off |
| 0 | 1 | Off | On |

4. For positive voltage control, external DC blocking capacitors are required on all RF ports.
5. Differential voltage, $\mathrm{V}($ state 1$)-\mathrm{V}$ (state 0 ), must be +2.7 V minimum, but must not exceed 8.5 V .
6. $0=-5 \mathrm{~V}$ to $+2.3 \mathrm{~V}, 1=-2.3 \mathrm{~V}$ to +5 V .

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## SC-70 Plastic Package



## Qualification

Qualified to M/A-COM specification REL-201, Process Flow -2.

## Handling Procedures

The following precautions should be observed to avoid damage:

## Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

Typical Performance Curves vs. Frequency, 39 pF

Insertion Loss


Return Loss


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Isolation


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